

Instructor: Jason Silver

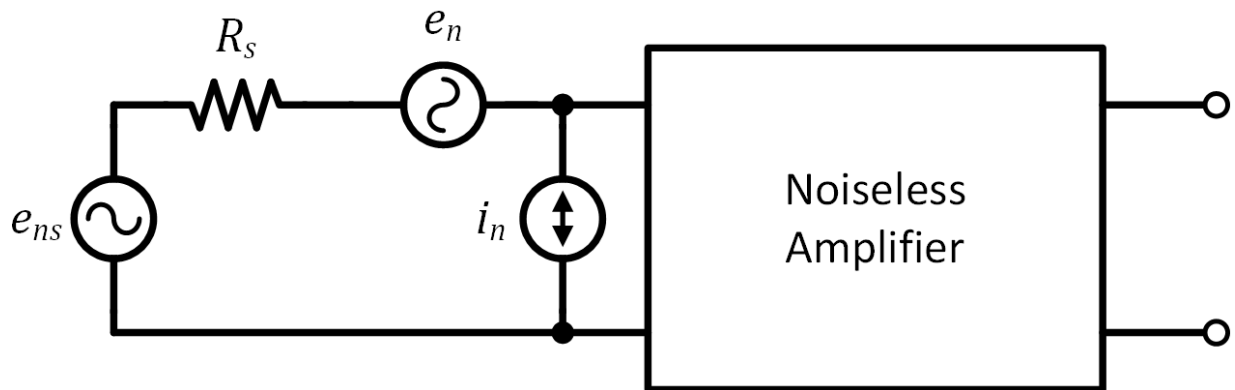
Midterm (100 points)

Due Sunday, May 16 (Submit on Canvas as a Jupyter Notebook or PDF)

Show all work

```
In [1]: 1 import numpy as np
        2 from scipy import integrate
        3 k = 1.38e-23
        4 T = 300
        5 q = 1.602e-19
        6 V_T = k*T/q
```

**Problem 1: Noise figure (25 points)**



**Figure 1. Amplifier noise model**

An amplifier datasheet provides noise measurements that show it has a noise figure of  $3\text{ dB}$  for  $R_s = 100\Omega$  and  $R_s = 10\text{ k}\Omega$  (same noise figure for both values of  $R_s$ ) at  $T = 300\text{ K}$  and  $f = 10\text{ kHz}$ .

**a)** Assuming all noise sources are white and  $e_n$  and  $i_n$  are uncorrelated, determine  $e_n$  and  $i_n$  at  $10\text{ kHz}$  from the noise figure data. (10 points)

$$\text{NF} = 10 \log F = 10 \log \left[ 1 + \frac{e_n^2 + R_s^2 i_n^2}{e_{ns}^2} \right]$$

$$\text{NF} = 3 \text{ dB} \rightarrow F \approx 2$$

$$2 = 1 + \frac{e_n^2 + R_s^2 i_n^2}{e_{ns}^2}$$

$$1 = \frac{e_n^2 + R_s^2 i_n^2}{4kTR_s\Delta f} \bigg|_{R_s=100\Omega, 10\text{ k}\Omega}$$

$$4kT \cdot 100 = e_n^2 + 100^2 i_n^2 \quad \text{and} \quad 4kT \cdot 10000 = e_n^2 + 10000^2 i_n^2$$

$$4kT = \frac{e_n^2}{100} + 100 i_n^2 \quad \text{and} \quad 4kT = \frac{e_n^2}{10000} + 10000 i_n^2$$

$$\begin{aligned} \frac{e_n^2}{100} + 100 i_n^2 &= \frac{e_n^2}{10000} + 10000 i_n^2 \\ e_n &= 1000 i_n \end{aligned}$$

$$e_n = 1.28 \text{ nV}$$

$$i_n = 1.28 \text{ pV}$$

b) What are the optimum source resistance  $R_{opt}$  of the amplifier and the corresponding minimum noise figure  $NF_{min}$ ? (5 points)

#### From Notes

- To minimize the noise factor/figure, we can take the first derivative of  $F$  with respect to the source impedance and set it equal to zero. Assuming  $Z_s = R_s$  (no reactive components), this yields

$$-\frac{e_n^2}{R_{opt}^2} + i_n^2 = 0$$

- From which we find the optimum source resistance to be

$$R_{opt} = \frac{e_n}{i_n}$$

- The noise factor corresponding to  $R_{opt}$  is thus

$$F_{opt} = 1 + \frac{e_n^2 + R_{opt}^2 i_n^2}{4kT R_{opt} \Delta f} = 1 + \frac{2e_n^2}{4kT \Delta f e_n / i_n} = 1 + \frac{e_n \cdot i_n}{2kT \Delta f}$$

```
In [2]: 1 e_n = 1.28*1e-9
        2 i_n = 1.28*1e-12
```

```
In [3]: 1 Rs = e_n/i_n
        2 F = 1 + (e_n*i_n)/(2*k*T)
        3 NF = 10*np.log10(F)
        4 print(f'Rs = {round(Rs)}, F = {round(F,2)}, Noise Figure = {round(NF,2)} dB')
```

Rs = 1000, F = 1.2, Noise Figure = 0.78 dB

$$R_{opt} = \frac{e_n}{i_n} = 1000 \Omega$$

$$\begin{aligned} F_{opt} &= 1 + \frac{e_n \cdot i_n}{2kT \Delta f} \\ &= 1 + \frac{(1.28 \cdot 10^{-9}) \cdot (1.28 \cdot 10^{-12})}{2kT} = 1.2 \end{aligned}$$

$$NF_{min} = 10 \log(1.2) = 0.78 \text{ dB}$$

c) Upon measuring the output noise of the amplifier with  $R_s = 0$ , you find that it has a  $1/f$  noise corner of  $1\text{ kHz}$ . What is the noise figure at  $100\text{ Hz}$  for  $R_s = R_{opt}$ ? (10 points)

```
In [4]: 1 e_n = 1.28*1e-9
        2 i_n = 1.28*1e-12
```

```
In [5]: 1 Rs = e_n/i_n
        2 F = (1 + (e_n*i_n)/(2*k*T))*(1+1000/100)
        3 NF = 10*np.log10(F)
        4 print(f'Rs = {round(Rs)}, F = {round(F,2)}, Noise Figure = {round(NF,2)} dB')
```

Rs = 1000, F = 13.18, Noise Figure = 11.2 dB

$$\begin{aligned} \text{NF} &= 10 \log \left[ F_{opt} \left( 1 + \frac{f_c}{\Delta f} \right) \right] \text{ where } \Delta f = 100\text{ Hz} \\ &= 10 \log \left[ \left( 1 + \frac{e_n \cdot i_n}{2kT} \right) \left( 1 + \frac{f_c}{\Delta f} \right) \right] \\ &= 10 \log \left[ \left( 1 + \frac{0.128 \cdot 10^{-6} \cdot 0.128 \cdot 10^{-9}}{2kT} \right) \left( 1 + \frac{1000}{100} \right) \right] \\ &= 10 \log[13.18] \\ &= 11.2 \text{ dB} \end{aligned}$$

## Problem 2: Noise in opamp circuits (25 points)

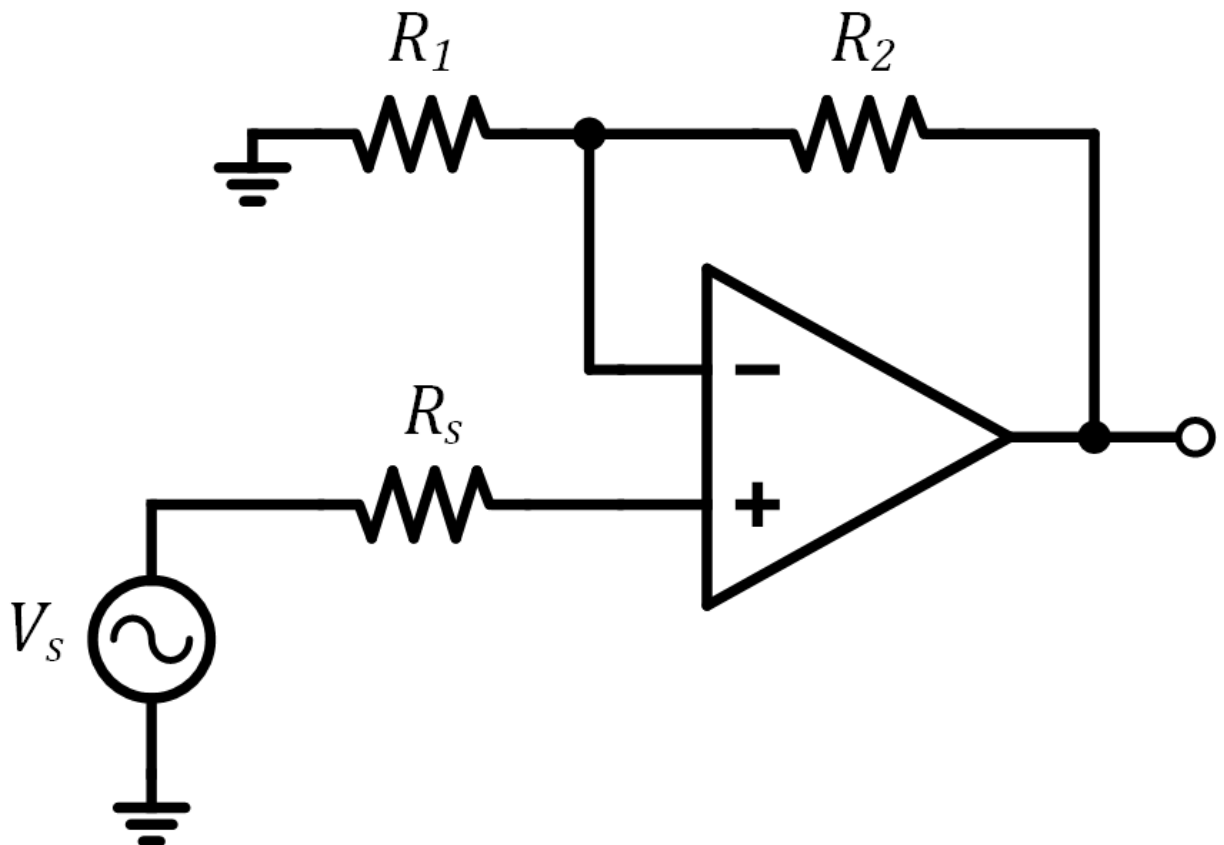


Figure 2. Non-inverting amplifier with source resistance

For the non-inverting amplifier in Fig. 2, suppose you have a choice between two opamps. Opamp A has  $e_{na} = 10nV/\sqrt{Hz}$  and  $i_{na} = 10pA/\sqrt{Hz}$ , while opamp B has  $e_{na} = 5nV/\sqrt{Hz}$  and  $i_{na} = 0.5pA/\sqrt{Hz}$ .

a) What is the optimum source resistance for each opamp and its corresponding minimum noise figure? If  $R_s = 1k\Omega$ , which opamp should you use to minimize noise figure? (10 points)

$$G = 1 + \frac{R_2}{R_1}$$

$$e_{n,out}^2 = 4kTR_s G^2 + e_n^2 G^2 + 4kTR_2 + 4kTR_1 \left(\frac{R_2^2}{R_1^2}\right) + i_n^2 R_s^2 G^2 + i_n^2 R_2^2$$

$$e_{ns}^2 = 4kTR_s$$

$$F = \frac{4kTR_s G^2 + e_n^2 G^2 + 4kTR_2 + 4kTR_1 \left(\frac{R_2^2}{R_1^2}\right) + i_n^2 R_s^2 G^2 + i_n^2 R_2^2}{4kTR_s}$$

$$\frac{\partial F}{\partial R_s} = -\frac{e_n^2 G^2}{R_{opt}^2} - \frac{R_2}{R_{opt}^2} - \frac{\left(\frac{R_2^2}{R_1}\right)}{R_{opt}^2} + i_n^2 G^2 - \frac{i_n^2 R_2^2}{R_{opt}^2} = 0$$

$$R_{opt} = \frac{e_n^2 G^2 + R_2 + \left(\frac{R_2^2}{R_1}\right) + i_n^2 R_2^2}{i_n^2 G^2}$$

$$R_{opt} \Big|_{R_1, R_2 = noiseless} = \frac{e_n^2 G^2}{i_n^2 G^2} = \frac{e_n}{i_n}$$

$$F_{opt} = 1 + \frac{e_n^2 + R_{opt}^2 i_n^2}{4kTR_{opt}} = 1 + \frac{e_n \cdot i_n}{2kT}$$

```
In [6]: 1 e_n = 10*1e-9
        2 i_n = 10*1e-12
```

```
In [7]: 1 Rs = e_n/i_n
        2 F = 1 + (e_n*i_n)/(2*k*T)
        3 NF = 10*np.log10(F)
        4 print(f'Rs = {round(Rs)}, F = {round(F,2)}, Noise Figure = {round(NF,2)} dB')
```

Rs = 1000, F = 13.08, Noise Figure = 11.17 dB

$$R_{optA} = \frac{10 \cdot 10^{-9}}{10 \cdot 10^{-12}} = 1K\Omega$$

$$F_{optA} = 1 + \frac{(10 \cdot 10^{-9}) \cdot (10 \cdot 10^{-12})}{2kT} = 13.08$$

$$NF_{minA} = 10 \log [13.08] = 11.17 \text{ dB}$$

$$NF \Big|_{R_s=1000} = NF_{minA}$$

```
In [8]: 1 e_n = 5*1e-9
        2 i_n = 0.5*1e-12
```

```
In [9]: 1 Rs = e_n/i_n
2 F = 1 + (e_n*i_n)/(2*k*T)
3 NF = 10*np.log10(F)
4 print(f'Rs = {round(Rs)}, F = {round(F,2)}, Noise Figure = {round(NF,2)} dB')
```

Rs = 10000, F = 1.3, Noise Figure = 1.15 dB

```
In [10]: 1 Rs = 1000
2 F = 1 + ( e_n**2 + (Rs**2) * (i_n**2) )/(4*k*T*Rs)
3 NF = 10*np.log10(F)
4 print(f'Rs = {round(Rs)}, F = {round(F,2)}, Noise Figure = {round(NF,2)} dB')
```

Rs = 1000, F = 2.52, Noise Figure = 4.02 dB

$$R_{optB} = \frac{5 \cdot 10^{-9}}{0.5 \cdot 10^{-12}} = 10K\Omega$$

$$F_{optB} = 1 + \frac{(5 \cdot 10^{-9}) \cdot (0.5 \cdot 10^{-12})}{2kT} = 1.30$$

$$NF_{minB} = 10 \log [1.30] = 1.15 \text{ dB}$$

$$\begin{aligned} NF \Big|_{R_s=1000} &= 10 \log \left[ 1 + \frac{e_n^2 + R_s^2 i_n^2}{4kTR_s} \right] \\ &= 10 \log \left[ 1 + \frac{(5 \cdot 10^{-9})^2 + 1000^2 (0.5 \cdot 10^{-12})^2}{4kT \cdot 1000} \right] \\ &= 4.02 \text{ dB} \end{aligned}$$

**Response:** I would choose opamp B, because it still has a lower noise figure even though it's not at optimal source impedance.

**b)** You found an even better opamp with  $e_{na} = 2nV/\sqrt{Hz}$  and  $i_{na} = 1pA/\sqrt{Hz}$  and decided to use it instead of the first two. What is the noise figure of the amplifier if  $R_1 = 500\Omega$  and  $R_2 = 4.5k\Omega$ ? (7.5 points)

```
In [11]: 1 e_n = 2*1e-9
2 i_n = 1*1e-12
3 Rs = 1000 # e_n/i_n
4 R1 = 500
5 R2 = 4500
6 G = 1 + R2/R1
```

```
In [12]: 1 F = ( 4*k*T*Rs*G**2 + (e_n**2)*(G**2) + 4*k*T*R2 + \
2         4*k*T*R1*(R2**2)/(R1**2) + (i_n**2)*(Rs**2)*(G**2) + \
3         (i_n**2)*(R2**2) )/(4*k*T*Rs)
4 NF = 10*np.log10(F)
5 print(f'Rs = {round(Rs)}, F = {round(F,2)}, Noise Figure = {round(NF,2)} dB')
```

Rs = 1000, F = 176.42, Noise Figure = 22.47 dB

Assume  $R_s = R_{opt}$

$$G = 1 + \frac{R_2}{R_1} = 1 + \frac{4500}{500} = 10$$

$$F = \frac{4kTR_s G^2 + e_n^2 G^2 + 4kTR_2 + 4kTR_1 \left(\frac{R_2^2}{R_1^2}\right) + i_n^2 R_s^2 G^2 + i_n^2 R_2^2}{4kTR_s}$$

$$F = \frac{(4kT \cdot 1000 \cdot 10^2) + (2 \cdot 10^{-9})^2 10^2 + (4kT \cdot 4500) + 4kT \cdot 500 \left(\frac{4500^2}{500^2}\right) + (1 \cdot 10^{-12})^2 1000^2 10^2 + (1 \cdot 10^{-12})^2 4500^2}{4kT(1000)}$$

$$F = 176.42$$

$$NF = 10 \log [147.27] = 22.47 \text{ dB}$$

c) If the transit frequency of the opamp is  $10 \text{ MHz}$  and its  $1/f$  corner is  $10 \text{ kHz}$ , what is the signal-to-noise ratio for an input signal given by  $v_{in} = v_a \cdot \sin(\omega_0 t)$ , where  $v_a = 1 \text{ mV}$  and  $\omega_0 = 2\pi \cdot 1 \text{ kHz}$ ? (7.5 points)

```
In [13]: 1 e_nout_sq = 4*k*T*Rs*G**2 + (e_n**2)*(G**2) + 4*k*T*R2 + \
2         4*k*T*R1*(R2**2)/(R1**2) + (i_n**2)*(Rs**2)*(G**2) + \
3         (i_n**2)*(R2**2)
4 print(f'Power spectral density = {round(e_nout_sq,18)} V^2/Hz')
```

Power spectral density = 2.921e-15 V^2/Hz

```
In [14]: 1 beta = 1/10
2 f_enb = (np.pi/2)*(beta)*(10*1e6)
3 print(f'Noise bandwidth = {round(f_enb)} Hz')
```

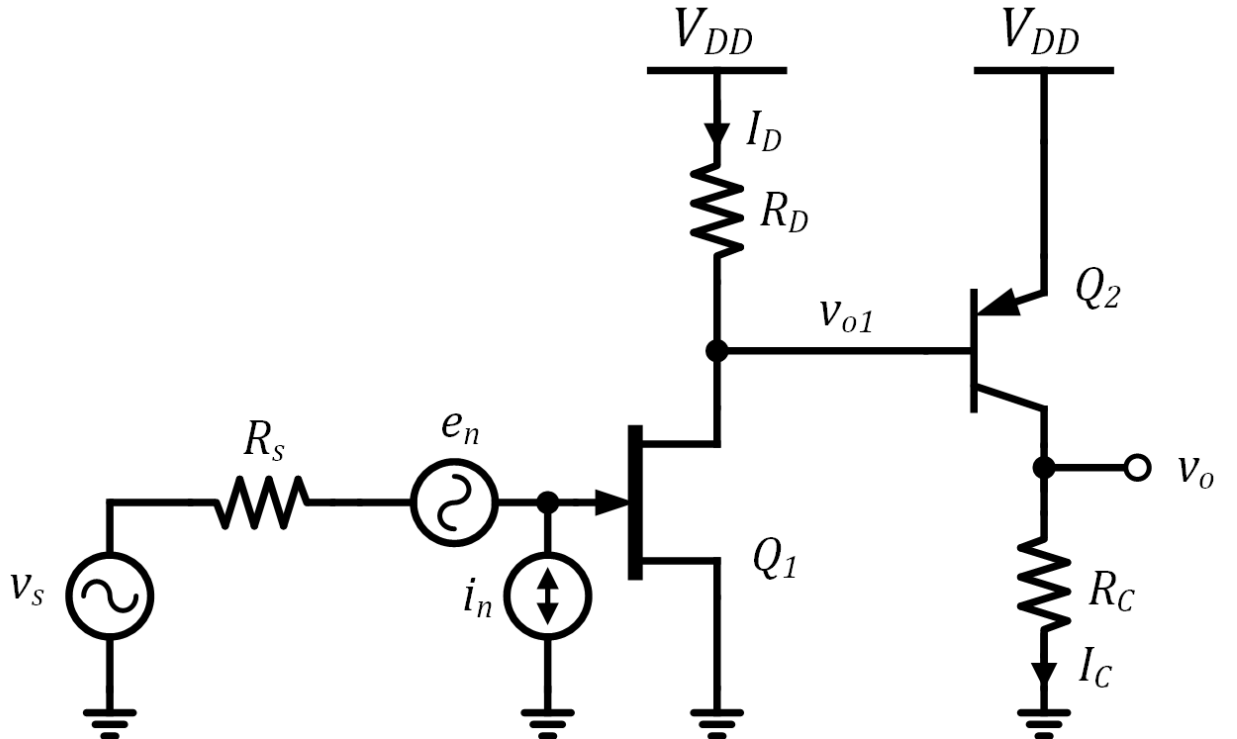
Noise bandwidth = 1570796 Hz

```
In [15]: 1 v_srms = 0.707*1e-3
2 v_nrms = 7.07*1e-6
3 SNR = 20*np.log10(v_srms/v_nrms)
4 print(f'Signal-to-noise ratio = {round(SNR,2)} dB')
```

Signal-to-noise ratio = 40.0 dB

$$\begin{aligned}
SNR &= 20 \log \frac{v_{s(rms)}}{v_{n,in(rms)}} \\
v_{s(rms)} &= 0.707 mV \\
v_{n,in(rms)} &= \frac{\sqrt{e_n^2 \cdot f_{enb}}}{1/\beta} \\
1/\beta &= G = 10 \\
e_n^2 &= 4kTR_s G^2 + e_n^2 G^2 + 4kTR_2 + 4kTR_1 \left( \frac{R_2^2}{R_1^2} \right) + i_n^2 R_s^2 G^2 + i_n^2 R_2^2 \\
e_n^2 \Big|_{(1/f)noise} &= e_n^2 \left( 1 + \frac{f_c}{\Delta f} \right) \\
f_{enb} &= \frac{\pi}{2} f_{3dB} \approx \frac{\pi}{2} \beta f_T \\
&= 1.57 \text{ MHz} \\
v_{n,in(rms)} &= \frac{\sqrt{\int_1^{1.57 \text{ MHz}} (2.92 \cdot 10^{-15}) \left( 1 + \frac{f_c}{f} \right) df}}{10} \text{ where } f_c = 10 \text{ kHz} \\
&= 7.07 \mu V \\
SNR &= 20 \log \left[ \frac{0.707 \cdot 10^{-3}}{7.07 \cdot 10^{-6}} \right] = 20 \log [100] \\
&= 40 \text{ dB}
\end{aligned}$$

**Problem 3: Low-noise amplifier design (25 points)**



**Figure 3. CS-CE Amplifier**

As shown in Fig. 3, a common-source amplifier can be combined with a common-emitter amplifier for high input impedance and high gain (biasing circuitry not shown).

Unless otherwise specified, assume only drain current thermal noise for  $Q_1$  and base/collector shot noise for  $Q_2$  (i.e. ignore  $1/f$  noise and assume  $i_n = 0$  for  $Q_1$  and  $r_b = 0$  for  $Q_2$ ). Ignore all capacitances except  $C_L$ .

For both transistors, assume  $r_o \rightarrow \infty$ .

Use  $\gamma = 2/3$ ,  $T = 300K$ , and  $\beta = I_C/I_B = 200$  for  $Q_2$  for your calculations.

**a)** Noise measurements of  $Q_1$  reveal that  $e_n = 3nV/\sqrt{Hz}$  for  $I_D = 100\mu A$ . What is the corresponding transconductance efficiency,  $g_m/I_D$ ? (5 points)

In [16]:

```
1 I_D = 100 * 1e-6
2 e_n = 3*1e-9
3 gamma = 2/3
4 gm = 4*k*T*gamma/(e_n**2)
5 print(f'Transconductance gm = {round(gm,4)}')
6 print(f'Transconductance efficiency gm/I_D = {round(gm/I_D,2)}')
```

Transconductance gm = 0.0012

Transconductance efficiency gm/I\_D = 12.27

$$I_D = 100 \cdot 10^{-6}$$

$$e_n^2 = \frac{i_{nd}^2}{g_m^2} = \frac{4kT\gamma g_m}{g_m^2} = \frac{4kT\gamma}{g_m}$$

$$g_m = \frac{4kT\gamma}{e_n^2} = \frac{4kT(2/3)}{(3 \cdot 10^{-9})^2} = 0.0012$$

$$\frac{g_m}{I_D} = \frac{0.0012}{100 \cdot 10^{-6}} = 12.27$$

**b)** Assuming the  $g_m/I_D$  value determined in part **a)**, determine values for  $I_D$  and  $R_D$  that give an input-referred voltage noise density of the common-source stage to be  $e_{n1} = 1nV/\sqrt{Hz}$  and a voltage gain of  $20dB$ . (10 points)

In [17]:

```
1 R_D = 10/gm
2 print(f'R_D = {round(R_D,2)} Ohms')
```

R\_D = 8152.17 Ohms

In [18]:

```
1 I_D = (4*k*T*(2/3))/(12.27 * (1*1e-9)**2)
2 print(f'I_D = {round(I_D,6)} A')
```

I\_D = 0.0009 A

$$|A_v| = g_m(r_o \parallel R_D) \approx g_m R_D$$

$$10 = g_m R_D$$

$$R_D = \frac{10}{g_m} = \frac{10}{0.0012} = 8152.17\Omega$$

Assume only drain current thermal noise



$$\begin{aligned}
e_n^2 &= \frac{i_{nd}^2}{g_m^2} = \frac{4kT\gamma}{g_m} \\
e_n^2 &= \frac{4kT\gamma}{(g_m/I_D) \cdot I_D} \\
(1nV/\sqrt{Hz})^2 &= \frac{4kT\gamma}{(g_m/I_D) \cdot I_D} \\
(1nV/\sqrt{Hz})^2 &= \frac{4kT(2/3)}{(12.27) \cdot I_D} \\
I_D &= \frac{4kT(2/3)}{(12.27) \cdot (1nV/\sqrt{Hz})^2} \\
I_D &= 0.9 \text{ mA}
\end{aligned}$$


---

c) Design the common-emitter stage (i.e. determine  $I_C$  and  $R_C$ ) for a gain of  $20dB$  and such that with the addition of the second stage the total input-referred voltage noise is only 1% higher than the  $1nV/\sqrt{Hz}$  target. (10 points)

```
In [19]: 1 e_n2 = np.sqrt(10**2 * ((1.01*1e-9)**2 - (1*1e-9)**2))
          2 print(f'e_n2 = {round(e_n2,12)} V/sqrt(Hz)')
```

e\_n2 = 1.418e-09 V/sqrt(Hz)

```
In [20]: 1 beta = 200
          2 I_C = (4*k*T)/((1.42*1e-9)**2) * (V_T/2 + V_T/(2*beta))
          3 print(f'I_C = {round(I_C,5)} A')
```

I\_C = 0.00011 A

```
In [21]: 1 R_C = 10*V_T/I_C
          2 print(f'R_C = {round(R_C,2)} Ohms')
```

R\_C = 2423.15 Ohms

$$\begin{aligned}
r_e &= \frac{1}{g_m} = \frac{V_T}{I_C} \\
V_T &= 26 \text{ mV}
\end{aligned}$$


---

$$\begin{aligned}
e_{n,in1} &= 1nV/\sqrt{Hz} \\
\sqrt{e_{n,in1}^2 + \left(\frac{e_{n,in2}}{A_{c1}}\right)^2} &= 1.01nV/\sqrt{Hz} \\
e_{n,in1}^2 + \left(\frac{e_{n,in2}}{A_{c1}}\right)^2 &= (1.01nV/\sqrt{Hz})^2 \\
e_{n,in2}^2 &= A_{c1}^2 \cdot [(1.01nV/\sqrt{Hz})^2 - (1nV/\sqrt{Hz})^2] \\
e_{n,in2} &= \sqrt{10^2 \cdot (2.01 \cdot 10^{-20})} V/\sqrt{Hz} \\
e_{n,in2} &= 1.42nV/\sqrt{Hz}
\end{aligned}$$


---

Assume only base/collector shot noise

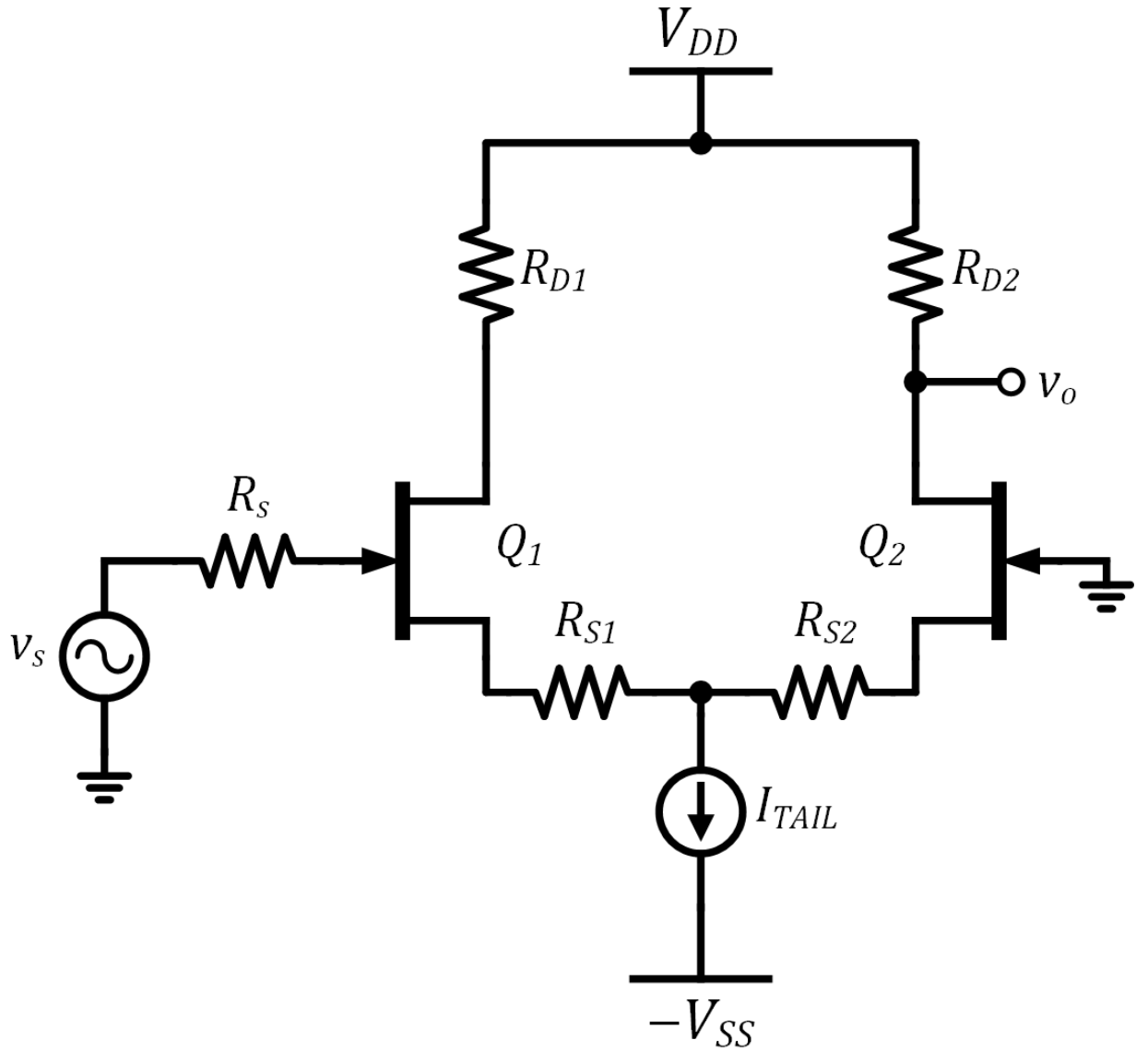
$$\begin{aligned}
e_n^2 &= i_{nc}^2 + i_{nb}^2 \\
e_n^2 &= 2qI_C r_e^2 + \frac{2qI_C}{\beta} r_e^2 \\
e_n^2 &= 4kT \left( \frac{r_e}{2} + \frac{r_e}{2\beta} \right) = 4kT \left( \frac{1}{2g_m} + \frac{1}{2\beta g_m} \right) \\
(1.42nV/\sqrt{Hz})^2 &= 4kT \left( \frac{1}{2g_m} + \frac{1}{2\beta g_m} \right) \\
(1.42nV/\sqrt{Hz})^2 &= 4kT \left( \frac{V_T}{2I_C} + \frac{V_T}{2\beta I_C} \right) \\
(1.42nV/\sqrt{Hz})^2 &= \frac{4kT}{I_C} \left( \frac{V_T}{2} + \frac{V_T}{2(200)} \right) \\
I_C &= \frac{4kT}{(1.42nV/\sqrt{Hz})^2} \left( \frac{26 \cdot 10^{-3}}{2} + \frac{26 \cdot 10^{-3}}{2(200)} \right) \\
I_C &= 0.11 \cdot 10^{-3} = 0.11 \text{ mA}
\end{aligned}$$


---

$$\begin{aligned}
|A_v| &= g_m(r_o \parallel R_C) \approx g_m R_C \\
10 &= g_m R_C \\
10 &= \frac{I_C}{V_T} R_C = \frac{I_C}{26 \cdot 10^{-3}} R_C \\
R_C &= \frac{26 \cdot 10^{-2}}{I_C} \Omega \\
R_C &= \frac{26 \cdot 10^{-2}}{0.11 \cdot 10^{-3}} \Omega \\
R_C &= 2423 \Omega
\end{aligned}$$


---

**Problem 4: DC-coupled differential amplifier (25 points)**



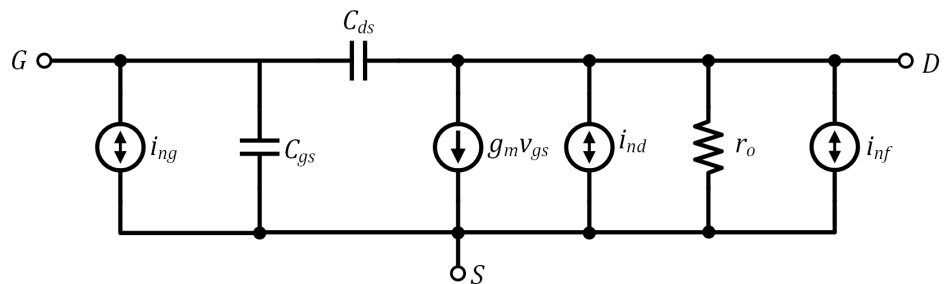
**Figure 4. DC-coupled differential amplifier**

The JFET differential pair in Fig. 4 is to be used for a DC-coupled sensor application.

$I_{TAIL}$  is an ideal current source with  $R_{out} \rightarrow \infty$ .

Unless otherwise specified, assume only drain current thermal noise for  $Q_1$  and  $Q_2$  (i.e. ignore  $1/f$  noise and assume  $i_{ng} = 0$  for  $Q_1$  and  $Q_2$ ). Ignore all capacitances.

For both transistors, assume  $r_o \rightarrow \infty$ ,  $\gamma = 2/3$ , and  $g_m/I_D = 10\text{S/A}$ .  $T = 300\text{K}$ .



**a)** Determine an expression for the input-referred voltage noise density of the amplifier,  $e_n$ , in terms of  $R_D$ ,  $R_{S1}$ ,  $R_{S2}$ ,  $I_{TAIL}$ ,  $\gamma$ , and  $kT$ . Do NOT assume balanced operation for noise analysis. (15 points)

Assume  $i_{ng} = 0$

$$e_{n,in} = \frac{e_{n,out}}{|A_v|}$$

$$|A_v| \approx \frac{R_D}{2R_S}$$

$$e_{n,out} = \sqrt{R_D^2 \cdot (i_{nd_1}^2 + i_{nRD_2}^2)}$$

$$e_{n,out} = \sqrt{R_D^2 \cdot (4kT\gamma g_{m1} + \frac{4kT}{R_{D_2}})}$$

$$e_{n,in} = \frac{\sqrt{R_D^2 \cdot (4kT\gamma g_{m1} + \frac{4kT}{R_{D_2}})}}{|A_v|}$$

**b)** Calculate the input-referred noise density if  $I_{tail} = 1mA$ ,  $R_D = 10k\Omega$ , and  $R_{S1} = R_{S2} = 1k\Omega$ . (10 points)

$$I_D \approx I_{tail}$$

$$|A_v| \approx \frac{R_D}{2R_S} = 5$$

$$\begin{aligned} g_m &= \frac{g_m}{I_D} I_D \\ &= 10 \cdot 1mA \\ &= 0.01S \end{aligned}$$

```
In [22]: 1 gamma = (2/3)
          2 Itail = 1*1e-3
          3 R_D = 10*1e3
          4 Rs1 = 1000
          5 Rs2 = 1000
          6 G = R_D/Rs1/2
          7 gm = 0.01
```

```
In [23]: 1 e_nout = np.sqrt(R_D**2 * (4*k*T*gamma*gm + 4*k*T/R_D))
          2 e_nin = e_nout/G
          3 print(f'Input-referred noise density = {round(e_nin,12)} V/sqrt(Hz)')
```

Input-referred noise density = 2.1171e-08 V/sqrt(Hz)

```
In [ ]: 1
```